

+3.3V, 622Mbps SDH/SONET Laser Driver with Current Monitors and APC

General Description

The MAX3669 is a complete, +3.3V laser driver with automatic power control (APC) circuitry for SDH/SONET applications up to 622Mbps. It accepts differential PECL inputs, provides bias and modulation currents, and operates over a temperature range from -40°C to +85°C.

An APC feedback loop is incorporated to maintain a constant average optical power over temperature and lifetime. The wide modulation current range from 5mA to 75mA and bias current of 1mA to 80mA are easy to program, making this product ideal for use in various SDH/SONET applications. Two pins are provided to monitor the current levels in the laser: BIASMON with current proportional to laser bias current, and MODMON with current proportional to laser modulation.

The MAX3669 also provides enable control and a failure-monitor output to indicate when the APC loop is unable to maintain the average optical power. The MAX3669 is available in 4mm x 4mm 24-pin thin QFN and 5mm x 5mm 32-pin TQFP packages.

Applications

622Mbps SDH/SONET Access Nodes

Laser Driver Transmitters

Section Regenerators

Features

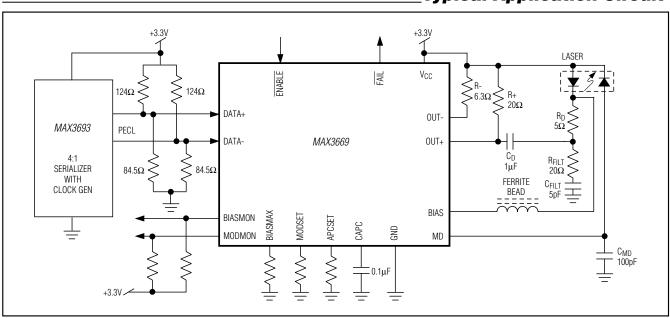
- ♦ +3.3V or +5.0V Single-Supply Operation
- ♦ 40mA Supply Current at +3.3V
- ♦ Programmable Bias Current from 1mA to 80mA
- ♦ Programmable Modulation Current from 5mA to 75mA
- **♦** Bias Current and Modulation Current Monitors
- ♦ 200ps Rise/Fall Time
- ♦ Automatic Average Power Control with Failure Monitor
- Complies with ANSI, ITU, and Bellcore SONET/SDH Specifications
- **♦ Enable Control**

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX3669ETG	-40°C to +85°C	24 TQFN-EP*
MAX3669ETG+	-40°C to +85°C	24 TQFN-EP*
MAX3669EHJ	-40°C to +85°C	32 TQFP
MAX3669EHJ+	-40°C to +85°C	32 TQFP

⁺Denotes a lead(Pb)-free/RoHS-compliant package. *EP = Exposed pad.

Typical Application Circuit



Pin Configurations appear at end of data sheet.

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ABSOLUTE MAXIMUM RATINGS

Supply Voltage, VCC -0.5V to +7.0V Current into BIAS -20mA to +150mA Current into OUT+, OUT- -20mA to +100mA Current into MD -5mA to +5mA Voltage at DATA+, DATA-, ENABLE, FAIL, BIASMON, MODMON -0.5V to (VCC + 0.5V) Voltage at OUT+, OUT- +1.5V to (VCC + 1.5V)	Voltage at BIAS
Voltage at OUT+, OUT+1.5V to (V _{CC} + 1.5V) Voltage at MODSET, APCSET, BIASMAX, CAPC0.5V to +3.0V	Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +3.14V \text{ to } +5.5V, T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{CC} = +3.3V, T_A = +25^{\circ}\text{C.})$

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Current		(Note 1)			40	60	mA
Bias Current Range	IBIAS	V _{BIAS} = V _{CC} - 1.6V		1		80	mA
Bias Off Current		ENABLE = low (Note 2	2)			100	μΑ
Bias Current Stability		APC open loop	I _{BIAS} = 80mA		255		ppm/°C
Bias Current Stability		APC open loop	I _{BIAS} = 1mA		815		ррпі, С
Bias Current Absolute Accuracy		APC open loop		-15		+15	%
Differential Input Voltage	V _{ID}	Figure 1		200		1600	mV _{P-P}
Common-Mode Input Voltage	VICM	PECL compatible		V _{CC} - 1.49	V _{CC} - 1.32	V _{CC} - V _{ID} /4	V
DATA+, DATA- Input Current	I _{IN}			-1		+10	μΑ
Monitor Diode Current Stability		(Note 3)	I _{MD} = 1mA	-480	-50	+480	ppm/°C
			I _{MD} = 18μA (Note 4)		35		
Monitor Diode Current			•	-15		+15	%
Absolute Accuracy				-10		T 10	/6
DC Monitor Diode Current	IMD			18		1000	μΑ
BIASMON to IBIAS Gain	ABIAS	I _{BIAS} /I _{BIASMON}			38		mA/mA
MODMON to I _{MOD} Gain	AMOD	IMOD/IMODMON			29		mA/mA
Monitor Diode Input Voltage (MD Pin)	V _{MD}				0.8		V
TTL Input High Voltage	VIH			2			V
TTL Input Low Voltage	VIL					0.8	V
TTL Output High Voltage (FAIL)	VoH	Sourcing 50µA		2.4	V _C C - 0.3	Vcc	V
TTL Output Low Voltage (FAIL)	V _{OL}	Sinking 100µA		0.1		0.44	V

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AC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +3.14V \text{ to } +5.5V, \text{ load as shown in Figure 2, } T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $V_{CC} = +3.3V, T_A = +25^{\circ}\text{C}$.) (Note 5)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Modulation Current Range	I _{MOD}	(Note 6)		5		75	mA
Modulation Off-Current		ENABLE = low (Note 2)	ENABLE = low (Note 2)			200	μΑ
Mandadation Comment Obeleith		$I_{MOD} = 75 \text{mA}$		-620	-165	+620	ppm/°C
Modulation Current Stability		I _{MOD} = 5mA (Note 4)			205		
Modulation Current Absolute Accuracy				-15		+15	%
Output Rise/Fall Time	t _{R,} t _F	20% to 80%, R _L = 10Ω 120Ω load	I _{MOD} = 5mA		100	200	20
			I _{MOD} = 75mA		230	375	ps
Jitter Generation (Peak-to-Peak)		(Note 7)				100	ps
Pulse-Width Distortion		(Notes 8, 9)	I _{MOD} = 5mA		70	155	no
(Peak-to-Peak)		$I_{MOD} = 75 \text{mA}$		10	135	- ps	
Enable/Start-Up Delay		Open loop			250		ns
Maximum Consecutive Identical Digits at 622Mbps	CID			80			Bits

- Note 1: Tested with $R_{MODSET} = 5.11 k\Omega$ ($I_{MOD} \approx 38 mA$), $R_{BIASMAX} = 4.56 k\Omega$ ($I_{BIAS} \approx 52 mA$), excluding I_{BIAS} and I_{MOD} .
- Note 2: Both the bias and modulation currents will be disabled if any of the current set pins are shorted to ground.
- **Note 3:** Guaranteed by design and characterization. This assumes that the laser to monitor diode transfer function does not change with temperature.
- **Note 4:** See the *Typical Operating Characteristics* for worst-case distributions.
- Note 5: AC characteristics are guaranteed by design and characterization.
- Note 6: Total I_{MOD} out of OUT+. See the *Design Procedure* section for information regarding current delivered to the laser.
- **Note 7:** Input signal is a 622Mbps, 2^{13} 1 PRBS with eighty inserted 0s.
- Note 8: Input signal is a 622Mbps, 11110000 pattern.
- Note 9: PWD = (wider pulse narrower pulse) / 2.

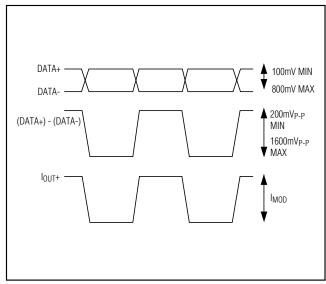


Figure 1. Required Input Signal and Output Polarity

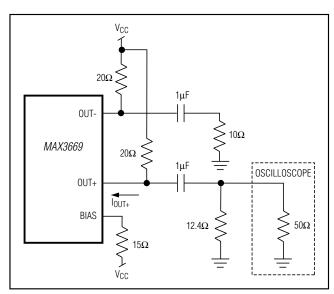


Figure 2. Output Termination for Characterization

20

I_{MOD} (mA)

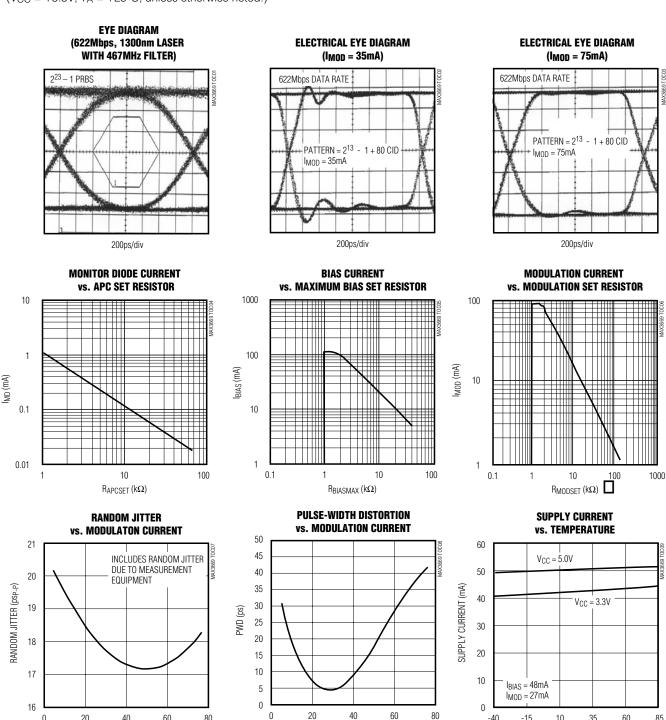
60

80

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Typical Operating Characteristics

 $(VCC = +3.3V, TA = +25^{\circ}C, unless otherwise noted.)$



I_{MOD} (mA)

-40

10

TEMPERATURE (°C)

35

60

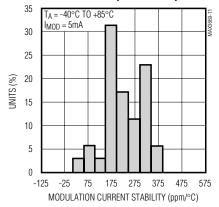
85

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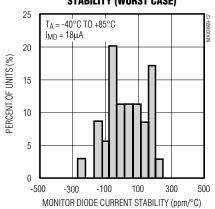
_Typical Operating Characteristics (continued)

 $(VCC = +3.3V, TA = +25^{\circ}C, unless otherwise noted.)$

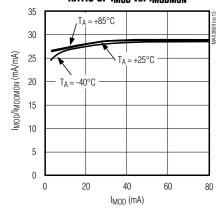
DISTRIBUTION OF MODULATION CURRENT STABILITY (WORST CASE)



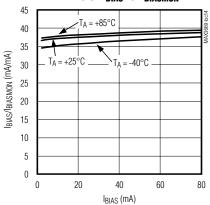
DISTRIBUTION OF MONITOR DIODE CURRENT STABILITY (WORST CASE)



RATIO OF IMOD vs. IMODMON



RATIO OF IBIAS VS. IBIASMON



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Pin Description

PIN TQFN-EP TQFP						
		NAME	FUNCTION			
1, 13, 16, 19	1, 2, 6, 15, 17, 20, 24	Vcc	Positive Supply Voltage			
2	3	DATA+	Positive PECL Data Input			
3	4	DATA-	Negative PECL Data Input			
4, 8, 11, 17, 22	5, 10, 14, 21, 22, 30	GND	Ground			
5	7	BIASMON	Sink Current Source. Proportional to the laser bias current.			
6	8	MODMON	Sink Current Source. Proportional to the laser modulation current.			
7	9	ENABLE	TTL/CMOS Enable Input. High for normal operation, low to disable laser bias and modulation currents. Internally pulled high.			
9	11	FAIL	TTL Output. Indicates APC failure when low. Internally pulled high through a $6k\Omega$			
10	12, 13, 26, 27, 28	N.C.	No Connection. Leave unconnected.			
12	16	BIAS	Laser Bias Current Output. Isolate from laser with a ferrite bead.			
14	18	OUT+	Positive Modulation Current Output. I _{MOD} flows into this pad when the input signal is high. Connect this pad to AC-coupling network.			
15	19	OUT-	Negative Modulation Current Output. I_{MOD} flows into this pad when the input signal is low. Connect this pad to V_{CC} through a 6.3Ω resistor.			
18	23	MD	Monitor Photodiode Connection. Connect this pad to the monitor photodiode anode. A capacitor to ground is required to filter high-speed AC monitor photocurrent.			
20	25	CAPC	APC Compensation Capacitor. A 0.1µF capacitor connected from this pad to ground controls the dominant pole of the APC feedback loop.			
21	29	APCSET	APC Set Resistor. A resistor connected from this pad to ground sets the desired average optical power. The resulting current is equal to the desired DC monitor diode current. Connect a $100k\Omega$ resistor from this pad to ground if APC is not used.			
23	31	MODSET	Modulation Set Resistor. A resistor from this pad to ground sets the laser modulation current.			
24	32	BIASMAX	Maximum Bias Set Resistor. A resistor from this pad to ground sets the maximum laser bias current. The APC function can subtract from this maximum value but cannot add to it. This resistor controls the bias-current level when the APC loop is not used.			
— EP Exposed Pad (TQFN only).		EP	Exposed Pad (TQFN only). The exposed paddle must be soldered to ground.			

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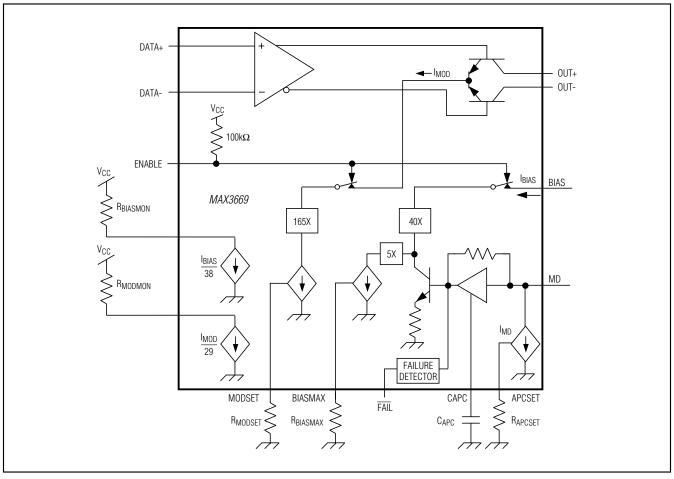


Figure 3. Functional Diagram

Detailed Description

The MAX3669 laser driver consists of three main parts: a high-speed modulation driver, a laser-biasing block with automatic power control (APC), and bias current and modulation current monitors. The circuit is optimized for low-voltage (+3.3V) operation.

The output stage is composed of a high-speed differential pair and a programmable modulation current source. Since the modulation output drives a maximum current of 75mA into the laser with a 230ps edge speed, large transient voltage spikes can be generated due to the parasitic inductance. These transients and the laser forward voltage leave insufficient headroom for the proper operation of the laser driver if the modulation output is DC-coupled to the laser diode. To solve this problem, the MAX3669's modulation output is designed to be

AC-coupled to the cathode of a laser diode. A simplified functional diagram is shown in Figure 3.

The MAX3669 modulation output is optimized for driving a $20\Omega \mid \mid 10\Omega$ load; the minimum required voltage at OUT+ is 2.0V. Modulation current swings of 75mA are possible. To interface with the laser diode, a damping resistor (RD) is required for impedance matching. An RC shunt network may be used to compensate for the laser-diode parasitic inductance, thereby improving the optical output aberrations and duty-cycle distortion.

At a 622Mbps data rate, any capacitive load at the cathode of a laser diode degrades the optical output performance. Since the BIAS output is directly connected to the laser cathode, minimize the parasitic capacitance associated with this pin by using an inductor to isolate the BIAS pin from the laser diode.

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Automatic Power Control

To maintain constant average optical power, the MAX3669 incorporates an APC loop to compensate for the changes in laser threshold current over temperature and lifetime. A back-facet photodiode mounted in the laser package is used to convert the optical power into a photocurrent. The APC loop adjusts the laser bias current so the monitor current is matched to a reference current set by RAPCSET. The time constant of the APC loop is determined by an external capacitor (CAPC). To eliminate the pattern-dependent jitter associated with the APC loop-time constant and to guarantee loop stability, the recommended value for CAPC is 0.1µF.

When the APC loop is functioning, the maximum allowable bias current is set by an external resistor, RBIASMAX. An APC failure flag (FAIL) is set low when the bias current can no longer be adjusted to achieve the desired average optical power.

APC closed-loop operation requires the user to set three currents with external resistors connected between ground and BIASMAX, MODSET, and APCSET. Detailed guidelines for these resistor settings are described in the *Design Procedure* section.

Bias and Modulation Monitors

The MAX3669 includes pins to monitor the output levels of bias and modulation current. BIASMON and MOD-MON sink current proportional to laser bias current and modulation current, respectively. By monitoring the current through RMODMON and RBIASMON, it is possible to monitor the levels of bias and modulation current in the laser (Figure 3).

Open-Loop Operation

If necessary, the MAX3669 is fully operational without APC. In this case, the laser current is directly set by two external resistors connected from ground to BIASMAX and MODSET. Connect a $100k\Omega$ resistor from APCSET to ground and leave MD open for open-loop operation.

Table 1. Optical Power Definition

PARAMETER	SYMBOL	RELATION
Average Power	Pavg	$P_{AVG} = (P_0 + P_1) / 2$
Extinction Ratio	r _e	$r_e = P_1 / P_0$
Optical Power High	P ₁	$P_1 = 2P_{AVG} \times r_e / (r_e + 1)$
Optical Power Low	P ₀	$P_0 = 2P_{AVG} / (r_e + 1)$
Optical Amplitude	P _{P-P}	$P_{P-P} = 2P_{AVG} (r_e - 1) / (r_e + 1)$
Laser Slope Efficiency	η	η = P _{P-P} / I _{MODL}
Laser Modulation Current	I _{MOD}	I _{MODL} = P _{P-P} / η

Enable Control

The MAX3669 incorporates a laser driver enable function. When ENABLE is low, both the bias and modulation currents are off. The typical laser enable time is 250ns.

APC Failure Monitor

The MAX3669 provides an APC failure monitor (TTL/CMOS) to indicate an APC loop tracking failure. FAIL is set low when the APC loop can no longer adjust the bias current to maintain the desired monitor current. This output is internally pulled up to VCC through a $6k\Omega$ resistor.

Short-Circuit Protection

The MAX3669 provides short-circuit protection for the modulation, bias, and monitor current sources. If either BIASMAX, MODSET, or APCSET is shorted to ground, the bias and modulation outputs will be turned off.

Design Procedure

When designing a laser transmitter, the optical output is usually expressed in terms of average power and extinction ratio. Table 1 gives the relationships that are helpful in converting between the optical average power and the modulation current. These relationships are valid if the average duty cycle of the optical waveform is 50%.

Programming the Modulation Current

In addition to being a function of R_{MODSET}, the modulation current delivered to the laser (I_{MODL}) also depends on the values of the series damping resistor (R_D), the shunt compensation resistance (R_{FILT}), and the laser diode's resistance (see *Typical Operating Circuit*).

The modulation current (assuming CFILT<<CD) into the laser diode can be represented by the following:

$$I_{MODL} = I_{MOD} \left[\frac{20\Omega}{20\Omega + (R_D + r_{LASER})} \right]$$

Assuming RD = 5Ω and rLASER = 5Ω , this equation is simplified to:

$$IMODL = IMOD(0.67)$$

For RD = 5.0Ω and a laser resistance of approximately 5Ω , see the Modulation Current vs. Modulation Set Resistor graph in the *Typical Operating Characteristics* and select the value of RMODSET that corresponds to the required current at +25°C.

Programming the Bias Current

When using the MAX3669 in open-loop operation, the bias current is determined by the RBIASMAX resistor. To select this resistor, determine the required bias current at +25°C. See the Bias Current vs. Maximum Bias Set

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Resistor graph in the *Typical Operating Characteristics* and select the value of RBIASMAX that corresponds to the required current at +25°C.

When using the MAX3669 in closed-loop operation, the RBIASMAX resistor sets the maximum bias current available to the laser diode over temperature and life. The APC loop can subtract from this maximum value but cannot add to it. See the Bias Current vs. Maximum Bias Set Resistor graph in the *Typical Operating Characteristics* and select the value of RBIASMAX that corresponds to the end-of-life bias current at +85°C.

Programming the APC Loop

When the MAX3669's APC feature is used, program the average optical power by adjusting the APCSET resistor. To select this resistor, determine the desired monitor current to be maintained over temperature and life. See the Monitor Diode Current vs. APC Set Resistor graph in the *Typical Operating Characteristics* and select the value of RAPCSET that corresponds to the required current.

Interfacing with the Laser Diode

To minimize optical output aberrations due to the laser parasitic inductance, an RC shunt network may be used (see *Typical Operating Circuit*). If R_L represents the laser diode resistance, the recommended total resistance for R_D + R_L is 10Ω . Starting values for coaxial lasers are R_{FILT} = 20Ω and C_{FILT} = 5pF. R_{FILT} and C_{FILT} should be experimentally adjusted to optimize the output waveform. A bypass capacitor should also be placed as close to the laser anode as possible for best performance.

Pattern-Dependent Jitter (PDJ)

When transmitting NRZ data with long strings of consecutive identical digits (CIDs), LF droop can contribute to PDJ. To minimize this PDJ, two external components must be properly chosen: capacitor CAPC, which dominates the APC loop time constant, and AC-coupling capacitor CD.

To filter out noise effects and guarantee loop stability, the recommended value for C_{APC} is $0.1\mu F$. This results in an APC loop bandwidth of 20kHz. Consequently, the PDJ associated with an APC loop time constant can be ignored.

The time constant associated with the DC blocking capacitor on IMOD will have an effect on PDJ. It is important that this time constant produce minimum droop for long consecutive bit streams.

Referring to Figure 4, the droop resulting from long time periods without transitions can be represented by the following equation:

$$(100\% - DROOP) = e^{\frac{-t}{\tau}}$$

AC-coupling of I_{MOD} results in a discharge level for τ that is equal to P_{AVG}. An overall droop of 6% relative to P_{p-p} equates to a 12% droop relative to P_{AVG}. To ensure a droop of less than 12% (6% relative to P_{p-p}), this equation can be solved for τ as follows:

$$\tau = \frac{-t}{\ln(1 - 0.12)} = 7.8t$$

If t₁ equals 80 consecutive unit intervals without a transition, the time constant associated with the DC blocking capacitor needs to be longer than:

$$\tau_{AC} \ge R_{AC}C_D = 7.8 \text{ (80 bits) (1.6ns/bit)} = 1.0 \mu s$$

RFILT can be ignored for CFILT<< C_D ; therefore, the estimated value of RAC is:

$$R_{AC} = 20\Omega \mid \mid (R_D + r_{LASER})$$

Assuming $R_D = 5\Omega$, and $r_{LASER} = 5\Omega$:

$$R_{AC} = 6.7\Omega$$

with $C_D = 1\mu F$, $\tau_{AC} = 6.7\mu s$.

Input Termination Requirement

The MAX3669 data inputs are PECL compatible. However, it is not necessary to drive the MAX3669 with a standard PECL signal. As long as the specified common-mode voltage and differential voltage swings are met, the MAX3669 will operate properly.

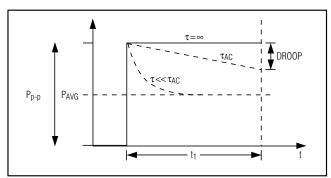


Figure 4. Droop

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Calculate Power Consumption

The total power dissipation of the MAX3669 can be estimated by the following:

$$P = V_{CC} \times I_{CC} + (V_{CC} - V_f) \times I_{BIAS} + I_{MOD} (V_{CC} - 20\Omega \times I_{MOD} / 2)$$

where IBIAS is the maximum bias current set by RBIAS-MAX, IMOD is the modulation current, and V_f is the typical laser forward voltage.

Applications Information

The following is an example of how to set up the MAX3669.

Select Laser

A communication-grade laser should be selected for 622Mbps applications. Assume the laser output average power is PAVG = 0dBm, the minimum extinction ratio is $r_e = 6.6$ (8.2dB), the operating temperature is -40°C to +85°C, and the laser diode has the following characteristics:

Wavelength: $\lambda = 1.3 \mu m$

Threshold Current: $I_{TH} = 22mA$ at +25°C

Threshold Temperature

 $\beta_{TH} = 1.3\%/^{\circ}C$ Coefficient: Laser to Monitor Transfer: $\rho_{MON} = 0.2A/W$ Laser Slope Efficiency: $\eta = 0.05 \text{mW/mA}$

at +25°C

Determine RAPCSET

The desired monitor diode current is estimated by $I_{MD} = P_{AVG} \times P_{MON} = 200 \mu A$. The Monitor Diode Current vs. APC Set Resistor graph in the Typical Operating Characteristics shows that R_{APCSET} should be $6k\Omega$.

Determine RMODSET

To achieve a minimum extinction ratio (r_e) of 6.6dB over temperature and lifetime, calculate the required extinction ratio at $+25^{\circ}$ C. Assuming $r_e = 20$, the peak-to-peak optical power $P_{p-p} = 1.81 \text{mW}$, according to Table 1. The required modulation current is 1.81(mW) / 0.05(mW/mA) = 36.2mA. The Modulation Current vs. Modulation Set Resistor graph (see Typical Operating Characteristics) shows that R_{MODSET} should be $5k\Omega$.

Determine RBIASMAX

Calculate the maximum threshold current (ITH(MAX)) at $T_A = +85^{\circ}C$ and end of life. Assuming $I_{TH(MAX)} =$ 50mA, the maximum bias current should be:

IBIAS = ITH(MAX) + IMOD / 2

In this example, IBIAS = 68.1mA. The Bias Current vs. Maximum Bias Set Resistor graph in the Typical Operating Characteristics shows that RBIASMAX should be $3k\Omega$.

Determine RBIASMON

To avoid saturating the current mirror of BIASMON, the voltage at this pin should not drop below (VCC - 1.6V). The resulting condition is:

$$R_{BIASMON} \le 1.6V \left(\frac{A_{BIAS}}{I_{BIASMAX}} \right)$$

where IBIASMAX is the maximum current expected for the application.

Determine RMODMON

To avoid saturating the current mirror of MODMON, the voltage at this pin should not drop below (VCC - 1V). The resulting condition is:

$$R_{MODMON} \le 1V \left(\frac{A_{MOD}}{I_{MOD}} \right)$$

Modulation Currents Exceeding 50mA

To drive modulation currents greater than 50mA at 3.3V, external pullup inductors (Figure 5) should be used to DC-bias the modulation output at VCC. Such a configuration isolates the laser forward voltage from the output circuitry and allows the output at OUT+ to swing above and below the supply voltage VCC.

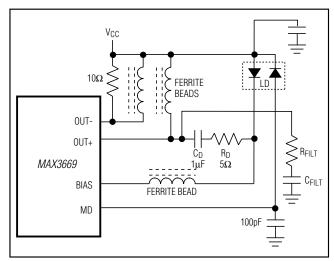


Figure 5. Output Termination for Maximum Modulation Current

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At +5V power supply, the headroom voltage for the MAX3669 is significantly improved. In this case, it is possible to achieve a modulation current of more than 50mA (using resistor pullups as shown in the *Typical Operating Circuit*). The MAX3669 can also be DC-coupled to a laser diode when operating at +5V supply; the voltage at OUT+ should be ≥2.0V for proper operation.

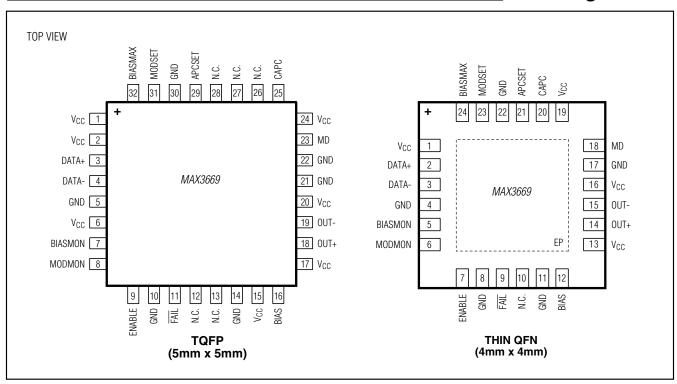
Layout Considerations

To minimize inductance, keep the connections between the MAX3669 output pins and LD as close as possible. Optimize the laser diode performance by placing a bypass capacitor as close as possible to the laser anode. Use good high-frequency layout techniques and multilayer boards with uninterrupted ground planes to minimize EMI and crosstalk.

Laser Safety and IEC 825

Using the MAX3669 laser driver alone does not ensure that a transmitter design is compliant with IEC 825. The entire transmitter circuit and component selections must be considered. Customers must determine the level of fault tolerance required by their application, recognizing that Maxim products are not designed or authorized for use as components in systems intended for surgical implant into the body, for applications intended to support or sustain life, or for any other application where the failure of a Maxim product could create a situation where personal injury or death may occur.

Pin Configurations



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__Chip Information

SUBSTRATE CONNECTED TO GND

_Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
TQFP	H32+2F	<u>21-0110</u>	90-0149
TQFN-EP	T2444+3	21-0139	90-0021

+3.3V, 622Mbps SDH/SONET Laser Driver with Current Monitors and APC

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	
6	1/13	Removed dice option from data sheet; removed the <i>Chip Topography</i> section; added the <i>Package Information</i> table	1, 2, 3, 11, 12



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многоканальный

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